

TECHNICAL DATA DATA SHEET 710, REV. C

HERMETIC POWER ULTRAFAST RECTIFIER

COMMON CATHODE

Add the letter "C" to the part number prefix – **SHDC** for package with ceramic seals.

DESCRIPTION: A 600 VOLT, 30 AMP, POWER ULTRAFAST RECTIFIER IN A HERMETIC TO-254 PACKAGE.

MAXIMUM RATINGS

All ratings are @ T_A = 25 °c unless otherwise specified

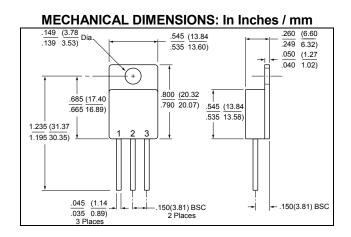
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	600	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ T _C =100 ^o C)	Io	30	Amps
PEAK SINGLE PULSE FORWARD CURRENT, 8.3 ms (per leg)	I _{FSM}	150	Amps
MAXIMUM THERMAL RESISTANCE PER LEG	$R_{ heta JC}$	2.2	°C/W
MAXIMUM POWER DISSIPATION	P _D	57	Watts
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-55 to + 150	°C

ELECTRICAL CHARACTRISTICS

(ALL RATINGS ARE PER LEG)

CHARACTRISTIC						
MAXIMUM FORWARD VOLTAGE DROP, Pulsed T _C = 25 °C (I _f = 15 Amps)	V_{f}	1.7	Volts			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed T _C = 125 °C (I _f = 15 Amps)		1.6	Volts			
MAXIMUM REVERSE CURRENT $T_C = 25 ^{\circ}\text{C I}_r \ @ 600 \text{PIV}$	I _r	10	μА			
MAXIMUM REVERSE CURRENT $T_C = 125 ^{\circ}\text{C} \text{I}_{\text{r}} @ 600 \text{PIV}$	I _r	1.0	mA			
MAXIMUM REVERSE RECOVERY TIME I _f = 0.5A, Ir = 1A, Irr = 0.25A	t _{rr}	60	nsec			

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TO-254

TYPE	PIN 1	PIN 2	PIN 3
ULTRAFAST RECTIFIER IN A	ANODE 1	COMMON	ANODE 2
TO-254 PACKAGE		CATHODE	

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